

2 N 3615	USA, Mot	Ge-P	LFS P, 80V, 7A, 77W, hFE=30...60	23a	TO-3	AL 102	23a	AL 102...103, AUJ 22, 2N2292...93, ++	
2 N 3616	USA, Mot	Ge-P	=2N3615: 100V	23a	TO-3	AL 102	23a	AL 102...103, 2N2290, 2N2293	
2 N 3617	USA, Mot	Ge-P	=2N3615: hFE=45...90	23a	TO-3	AL 102	23a	AL 102...103, AUJ 22, 2N2292...93, ++	
2 N 3618	USA, Mot	Ge-P	=2N3615: 100V, hFE=45...90	23a	TO-3	AL 102	23a	AL 102...103, 2N2290, 2N2293	
2 N 3619	Sca.Sol.Ssi	Si-N	S P, 75V, 2.5A, 7.5W(Tc=25°), >200MHz	2a	TO-5			BSS 15, BSV 84, BSX 64, 2N5320	
2 N 3620	Sca.Sol.Ssi	Si-N	S P, 75V, 5A, 7.5W, >200MHz	=49m				-	
2 N 3621	Sca.Sol.Ssi	Si-N	S P, 75V, 10A, 30W, >200MHz	49a	TO-61			-	
2 N 3622	Sca.Sol.Ssi	Si-N	S P, 75V, 10A, 30W, >200MHz	49m	TO-61			-	
2 N 3623	Sca.Sol.Ssi	Si-N	S P, 75V, 2.5A, 7.5W(Tc=25°), >200MHz	2a	TO-5			BSS 15, BSV 84, BSX 64, 2N5320	
2 N 3624	Sca.Sol.Ssi	Si-N	S P, 75V, 5A, 7.5W, >200MHz	=49m				-	
2 N 3625	Sca.Sol.Ssi	Si-N	S P, 75V, 10A, 30W, >200MHz	49a	TO-61			-	
2 N 3626	Sca.Sol.Ssi	Si-N	S P, 75V, 10A, 30W, >200MHz	49m	TO-61			-	
2 N 3627	Sca.Sol.Ssi	Si-N	S P, 100V, 2.5A, 7.5W(Tc=25°), >200MHz	2a	TO-39			BSS 15, BSV 84, BSX 64, 2N5320	
2 N 3628	Sca.Sol.Ssi	Si-N	S P, 100V, 5A, 7.5W, >200MHz	=49m				-	
2 N 3629	Sca.Sol.Ssi	Si-N	S P, 100V, 10A, 30W, >200MHz	49a	TO-61			-	
2 N 3630	Sca.Sol.Ssi	Si-N	S P, 100V, 10A, 30W, >200MHz	49m	TO-61			-	
2 N 3631	Six	MOS-N-FET-d	Uni, 20V, Idss>2mA, Up<6V	2a	TO-18			2N3797	
2 N 3632	USA, EUR	Si-N	VHF P, 65V, 3A, PQ=13.5W(175MHz)	49a	TO-60			-	
2 N 3633	USA	Si-N	SS, 15V, 0.05A, 0.3W, <9/9ns	2a	TO-18			BSV 89...92, BSX 27, BSX 44, 2N2475, ++	
2 N 3634(S)	USA, Mot, Tix	Si-P	LFS, 140/140V, 1A, 1W, >150MHz, hFE=50...150	2a	TO-5			BFT 19A, B, BFT 28(A...C), 2N5415	
2 N 3635(S)	USA, Mot, Tix	Si-P	=2N3634: hFE=100...300	2a	TO-5			BFT 19A, B, BFT 28(A...C), 2N5415	
2 N 3636(S)	USA, Mot, Tix	Si-P	=2N3634: 175/175V	2a	TO-5			BFT 19A, B, BFT 28A...C, 2N5415	
2 N 3637(S)	USA, Mot, Tix	Si-P	=2N3634: 175/175V, hFE=100...300	2a	TO-5			BFT 19A, B, BFT 28A...C, 2N5415	
2 N 3638(A)	Fch, Nsc, Sgs	Si-P	LFS, 25V, 0.5A, 0.3W, <90/170ns	8a	TO-105	BC 161	2a	BC 160...161, BC 303...304, 2N3072...73, ++	
2 N 3639	Fch, Nsc, Sgs	Si-P	S, 6V, 0.08A, 0.2W, <30/32ns	8a	TO-106			BSX 36	
2 N 3640	Fch, Nsc, Sgs	Si-P	=2N3639: 12V	8a	TO-106			BSX 36	
2 N 3641	Fch, Nsc, Sgs	Si-N	LFS, 60/30V, 0.5A, 0.35W, >250MHz, hFE>40	8a	TO-105	BC 141	2a	BC 337A, BC 637, BC 639, 2N3299...3300, ++	
2 N 3642	Fch, Nsc, Sgs	Si-N	=2N3641: 60/45V	8a	TO-105	BC 141	2a	BC 337A, BC 637, BC 639, 2N3299...3300, ++	
2 N 3643	Fch, Nsc, Sgs	Si-N	=2N3641: hFE=100...300	8a	TO-105	BC 141	2a	BC 337A, BC 637, BC 639, 2N3299...3300, ++	
2 N 3644	Fch, Nsc, Sgs	Si-P	LFS, 45V, 0.5A, 0.3W, >200MHz	8a	TO-105			BC 327, BC 638, BC 640, 2N3072...73, ++	
2 N 3645	Fch, Nsc, Sgs	Si-P	=2N3644: 60V	8a	TO-105			BC 327A, BC 638, BC 640, 2N3072...73, ++	
2 N 3646	Fch, Nsc, Sgs	Si-N	S, 40V, 0.2A, 0.2W, <25/35ns	8a	TO-106			BSS 10...11, BSX 19...20, 2N2368...69(A), ++	
2 N 3647	USA, Mot, Sgs	Si-N	=2N3510: 0.4W	2a	TO-46			*2N3510	
2 N 3648	USA, Mot, Sgs	Si-N	=2N3511: 0.4W	2a	TO-46			*2N3511	
2 N 3649	USA, Tag, Tho	F-Thy	50V, 25A(Tc=40°), 35A=, Igt/Ih<180/<150mA, tq<15µs	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3650		F-Thy	=2N3649: 100V	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3651		F-Thy	=2N3649: 200V	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3652		F-Thy	=2N3649: 300V	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3653		F-Thy	=2N3649: 400V	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3654		F-Thy	=2N3649: tq<10µs	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3655		F-Thy	=2N3650: tq<10µs	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3656		F-Thy	=2N3651: tq<10µs	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3657		F-Thy	=2N3652: tq<10µs	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3658		F-Thy	=2N3653: tq<10µs	21b	=TO-48			BTW 28/500R, CS 15, 9-04	
2 N 3659	USA	Si-N	S/Vid, 220V, 0.5A, 4W(Tc=25°), >50MHz	2a	TO-5			BSS 48...40, 2N3440, 2SD576	
2 N 3660	USA	Si-P	Uni, 40V, 1.5A, 5W(Tc=25°), >25MHz	2a	TO-5			BC 461, BCX 60, BSV 17, 2N5322...23, ++	
2 N 3661	USA	Si-P	=2N3660: 60V	2a	TO-5			BC 461, BCX 60, BSV 17, 2N5322...23, ++	
2 N 3662	Gen Nsc, Sem	Si-N	VHF, IF, 18V, 0.025A, 0.2W, 1000MHz	7c	TO-98	BF 199	7d	BF 225, BF 314, BF 502, BF 505, BF 507++	
2 N 3663	Gen Nsc, Sem	Si-N	VHF, IF, 30V, 0.025A, 0.2W, 1000MHz	7c	TO-98	BF 199	7d	BF 225, BF 314, BF 502, BF 505, BF 507++	
2 N 3664	Mot Sca	Si-N	HF/UHF Out, 60V, 0.5A, PQ>2.2W(250MHz)	49a	TO-102			-	
2 N 3665	USA, Nsc, Tix	Si-N	LFS, 120V, 1A, 0.3W, >60MHz, hFE=40...120	2a	TO-5			BSS 42...43, 2N2102, 2N2405, 2N3019...20++	
2 N 3666	USA, Nsc, Tix	Si-N	=2N3665: hFE=100...300	2a	TO-5			BSS 42...43, 2N2102, 2N2405, 2N3019...20++	
2 N 3667	USA	Si-N	S P, 50V, 15A, 117W, >0.5MHz	23a	TO-3			BD 315, BD 745, BDX 13, 2N3055, ++	
2 N 3668	Rca	50Hz-Thy	100V, 8A(Tc=80°), 12.5A=, Igt/Ih<40/<50mA	23a	TO-3			2N2575	
2 N 3669		50Hz-Thy	=2N3668: 200V	23a	TO-3			2N2576	
2 N 3670		50Hz-Thy	=2N3668: 400V	23a	TO-3			2N2578	
2 N 3671	USA, Fch	Si-P	S, 60V, 0.6A, 0.6W, 35/80ns	2a	TO-5			2SA717, 2SA742	
2 N 3672	USA, Fch	Si-P	=2N3671: 0.4W	2a	TO-18			BSW 24, 2N2906...07(A)	
2 N 3673	USA, Fch, Mot	Si-P	=2N3671: 0.35W	2a	TO-46			BSW 24, 2N2906...07(A)	
2 N 3675	USA, Tix	Si-N	S, 90/55V, 3A, 8.8W(Tc=25°), >1MHz	2a	TO-5			BSX 64, BUY 41, 2N4239, 2SC2214, ++	
2 N 3676	USA, Tix	Si-N	=2N3675: 90/90V	2a	TO-5			BSX 64, BUY 41, 2N4239, 2SC2214, ++	
2 N 3677	USA, Mot	Si-P	Chopper, 30/20/30V, 0.1A, 0.4W, >5MHz	2a	TO-46			2N2946	
2 N 3678	Fch, Nsc, ++	Si-N	Uni, 75V, 0.8A, 0.8W, <40/250ns	2a	TO-5			BSW 39, BSW 53...54, 2N2218...19A, 2N3444	
2 N 3679	Gen	UJT-P	0.25W, Ivs>4.2mA, η=0.8, Rbb<9.1kΩ	5	TO-72			-	
2 N 3680	USA, Sgs, Tix	Si-N	Dual, In, 60/50V, 0.03A, 0.6W, >60MHz, F<3dB(1kHz) hFE=150...600, ΔhFE=0.9...1, ΔUbe<3mV	TO-77	(CBE-EBC-)			BFX 70...72, 2N2060, 2N2223	
2 N 3681	Etc, Sca, Ssi	Si-N	UHF, 10V, 0.025A, 0.2W, >1000MHz	5g	TO-72			BF 377...378, BF 689, BF 763, 2N2857, ++	
2 N 3682	Tix	Si-N	SS, 40V, 0.2A, 0.36W, <12/-ns	2a	TO-18			BSS 10...11, BSX 19...20, 2N2368...69(A), ++	
2 N 3683	USA, Fch	Si-N	UHF, 30V, 0.03A, 0.2W, >1000MHz	5g	TO-72			BF 377...378, BF 689, BF 763, 2N2857, ++	
2 N 3684(A)	Isi, Nsc, ++	N-FET	Uni, In, 50V, Idss>2.5mA, Up<5V	5k	TO-72			BF 256A, BFS 71, 2N3822, 2N4221, ++	
2 N 3685(A)	Isi, Nsc, ++	N-FET	Uni, In, 50V, Idss>1mA, Up<3.5V	5k	TO-72			BFW 12, 2N4340, 2N5484	
2 N 3686(A)	Isi, Nsc, ++	N-FET	Uni, In, 50V, Idss>0.4mA, Up<2V	5k	TO-72			2N4339, 2N5358, 2SK83, 2SK193, 2SK195, ++	
2 N 3687(A)	Isi, Nsc, ++	N-FET	Uni, In, 50V, Idss>0.1mA, Up<1.2V	5k	TO-72			2N4117, 2SK92...93, 2SK103	
2 N 3688	Fch, Sgs	Si-N	VHF, IF, agc, 40V, 0.03A, 0.2W, >400MHz	8a	TO-106			BF 198, BF 225, BF 310, BF 367, BF 596++	
2 N 3689	Fch, Sgs	Si-N	VHF, IF, agc, 40V, 0.03A, 0.2W, >400MHz	8a	TO-106			BF 198, BF 225, BF 310, BF 367, BF 596++	
2 N 3690	Fch, Sgs	Si-N	VHF, IF, agc, 40V, 0.03A, 0.2W, >400MHz	8a	TO-106			BF 198, BF 225, BF 310, BF 367, BF 596++	
2 N 3691	USA, Mic, Sgs	Si-N	HF, 35V, 0.05A, 0.2W, 260MHz	8a	TO-106			BF 240...241, BF 254...255, BF 594...595, ++	
2 N 3692	USA, Mic, Sgs	Si-N	HF, 35V, 0.05A, 0.2W, 260MHz	8a	TO-106			BF 240...241, BF 254...255, BF 594...595, ++	
2 N 3693	USA, Mic, Sgs	Si-N	FM IF, 45V, 0.05A, 0.2W, 400MHz	8a	TO-106			BF 240...241, BF 254...255, BF 594...595, ++	
2 N 3694	USA, Mic, Sgs	Si-N	FM IF, 45V, 0.05A, 0.2W, 400MHz	8a	TO-106			BF 240...241, BF 254...255, BF 594...595, ++	
2 N 3695	Tsc	P-FET	Uni, In, 30V, Idss>1.75mA, Up<4.5V	5n	TO-72			2N2609	
2 N 3696	Tsc	P-FET	Uni, In, 30V, Idss>0.5mA, Up<3.2V	5n	TO-72			-	
2 N 3697	Tsc	P-FET	Uni, In, 30V, Idss>0.2mA, Up<1.8V	5n	TO-72			2N2843	
2 N 3698	Tsc	P-FET	Uni, In, 30V, Idss>0.05mA, Up<1.1V	5n	TO-72			-	
2 N 3700	USA, EUR	Si-N	Uni, 140V, 1A, 0.5W, 200MHz, hFE=100...300	2a	TO-18			BSS 59, 2SC2383, 2SC3228	
2 N 3701	USA, EUR	Si-N	=2N3700: hFE=40...120	2a	TO-18			BSS 59, 2SC2383, 2SC3228	
2 N 3702	USA, Aeg, Tix	Si-P	Uni, 40V, 0.2A, 0.3W, >100MHz, hFE=60...300	7c	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++	
2 N 3703	USA, Aeg, Tix	Si-P	=2N3702: 45V, hFE=30...150	7c	TO-92	BC 556	7a	BC 212, BC 257, BC 307, BC 557, ++	
2 N 3704	USA, Aeg, Tix	Si-N	Uni, 50V, 0.8A, 0.36W, >100MHz, hFE=100...300	7c	TO-92	BC 639	7c	BC 337, BC 637, BC 639, 2SD667, ++	
2 N 3705	USA, Aeg, Tix	Si-N	=2N3704: hFE=50...150	7c	TO-92	BC 639	7c	BC 337, BC 637, BC 639, 2SD667, ++	
2 N 3706	USA, Aeg, Tix	Si-N	=2N3704: 40V, hFE=30...600	7c	TO-92	BC 639	7c	BC 337, BC 635, BC 637, BC 639, ++	
2 N 3707	USA, Aeg, Tix	Si-N	LF Inp In, 30V, 0.03A, 0.36W, 80MHz	{2N4058	7c	TO-92	BC 550	7a	BC 169, BC 184, BC 239, BC 549, ++
2 N 3708	USA, Aeg, Tix	Si-N	LF, 30V, 0.03A, 0.36W, 80MHz, hFE=45...660	{2N4059...}	7c	TO-92	BC 550	7a	BC 168, BC 183, BC 238, BC 548, ++